

Fast IGBT in NPT-technology

- 75% lower *E*_{off} compared to previous generation combined with low conduction losses
- Short circuit withstand time 10 μ s
- Designed for:
 - Motor controls
 - Inverter
- NPT-Technology for 600V applications offers:
 - very tight parameter distribution
 - high ruggedness, temperature stable behaviour
 parallel switching capability
- Pb-free lead plating; RoHS compliant
- Qualified according to JEDEC² for target applications
- Complete product spectrum and PSpice Models : http://www.infineon.com/igbt/

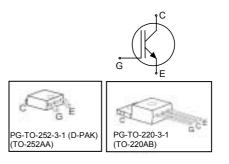
Туре	V _{CE}	I _c	V _{CE(sat)150°C}	Tj	Marking	Package
SGP04N60	600V	4A	2.3V	150°C	G04N60	PG-TO-220-3-1
SGD04N60	600V	4A	2.3V	150°C	G04N60	PG-TO-252-3-11

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V _{CE}	600	V
DC collector current	I _C		А
$T_{\rm C}$ = 25°C		9.4	
$T_{\rm C}$ = 100°C		4.9	
Pulsed collector current, t_p limited by T_{jmax}	I _{Cpuls}	19	
Turn off safe operating area	-	19	
$V_{CE} \le 600 \text{V}, \ T_{j} \le 150^{\circ} \text{C}$			
Gate-emitter voltage	V _{GE}	±20	V
Avalanche energy, single pulse	E _{AS}	25	mJ
$I_{\rm C}$ = 4 A, $V_{\rm CC}$ = 50 V, $R_{\rm GE}$ = 25 Ω ,			
start at $T_j = 25^{\circ}C$			
Short circuit withstand time ¹⁾	t _{sc}	10	μs
V_{GE} = 15V, $V_{\text{CC}} \le 600$ V, $T_{j} \le 150^{\circ}$ C			
Power dissipation	P _{tot}	50	W
$T_{\rm C}$ = 25°C			
Operating junction and storage temperature	$T_{\rm j}$, $T_{\rm stg}$	-55+150	°C
Soldering temperature, PG-TO-252: (reflow soldering, MSL3) Others: wavesoldering, 1.6mm (0.063 in.) from case for 10s	T _s	260 260	

² J-STD-020 and JESD-022

¹⁾ Allowed number of short circuits: <1000; time between short circuits: >1s.





Thermal Resistance

Parameter	Symbol	Conditions	Max. Value	Unit
Characteristic				•
IGBT thermal resistance,	$R_{ m thJC}$		2.5	K/W
junction – case				
Thermal resistance,	$R_{ m thJA}$	PG-TO-220-3-1	62	
junction – ambient				
SMD version, device on PCB ¹⁾	$R_{ m thJA}$	PG-TO-252-3-1	50	

Electrical Characteristic, at T_i = 25 °C, unless otherwise specified

Parameter	Symbol	Conditions		Value		Unit
Parameter	Symbol	Conditions	min.	Тур.	max.	
Static Characteristic	·					
Collector-emitter breakdown voltage	V _{(BR)CES}	$V_{\rm GE}$ =0V, $I_{\rm C}$ =500 μ A	600	-	-	V
Collector-emitter saturation voltage	V _{CE(sat)}	$V_{\rm GE}$ = 15V, $I_{\rm C}$ =4A				
		T _j =25°C	1.7	2.0	2.4	
		<i>T</i> _j =150°C	-	2.3	2.8	
Gate-emitter threshold voltage	V _{GE(th)}	$I_{\rm C} = 200 \mu {\rm A}, V_{\rm CE} = V_{\rm GE}$	3	4	5	
Zero gate voltage collector current	ICES	$V_{\rm CE}$ =600V, $V_{\rm GE}$ =0V				μA
		<i>T</i> _j =25°C	-	-	20	
		<i>T</i> _j =150°C	-	-	500	
Gate-emitter leakage current	I _{GES}	$V_{\rm CE} = 0 V, V_{\rm GE} = 20 V$	-	-	100	nA
Transconductance	g _{fs}	$V_{\rm CE}$ =20V, $I_{\rm C}$ =4A		3.1	-	S
Dynamic Characteristic						
Input capacitance	Ciss	V _{CE} =25V,	-	264	317	pF
Output capacitance	Coss	V _{GE} =0V,	-	29	35	
Reverse transfer capacitance	Crss	f=1MHz	-	17	20	
Gate charge	Q _{Gate}	V _{CC} =480V, <i>I</i> _C =4A	-	24	31	nC
		V _{GE} =15V				
Internal emitter inductance	L _E		-	7	-	nH
measured 5mm (0.197 in.) from case						
Short circuit collector current ²⁾	I _{C(SC)}	V_{GE} =15V, t_{SC} ≤10µs V_{CC} ≤ 600V, T_j ≤ 150°C	-	40	-	A

¹⁾ Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70μm thick) copper area for collector connection. PCB is vertical without blown air.
 ²⁾ Allowed number of short circuits: <1000; time between short circuits: >1s.



Switching Characteristic, Inductive Load, at T_i =25 °C

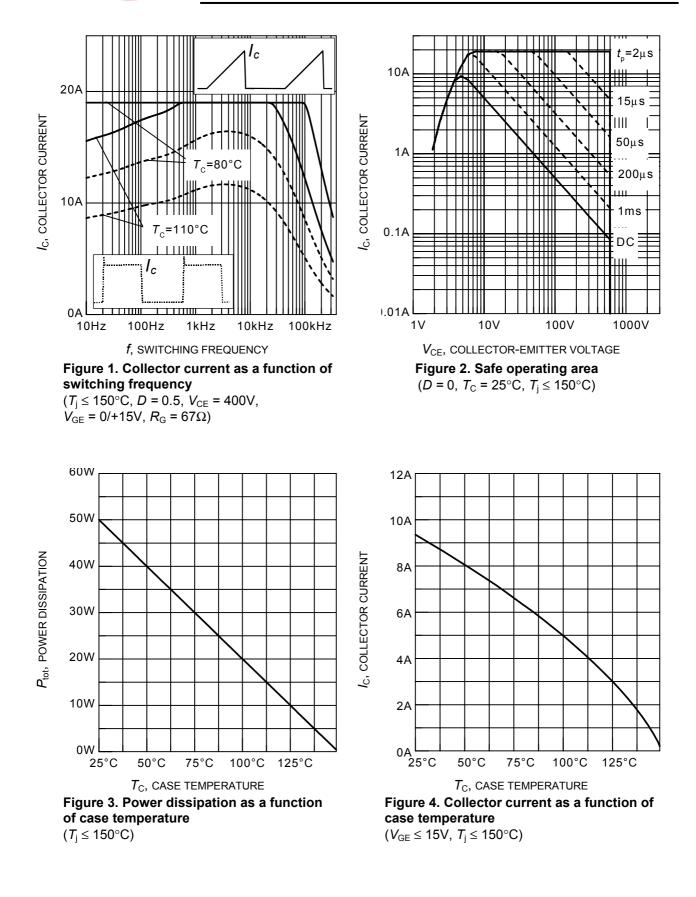
Parameter	Symbol	Conditions		Value		Linit
Farameter	Symbol	Conditions	min.	typ.	max.	Unit
IGBT Characteristic		·				
Turn-on delay time	t _{d(on)}	<i>T</i> _j =25°C,	-	22	26	ns
Rise time	t _r	V _{CC} =400V,I _C =4A, V _{GE} =0/15V,	-	15	18	
Turn-off delay time	$t_{d(off)}$	$R_{\rm G}$ =67 Ω ,	-	237	284	
Fall time	t _f	$L_{\sigma^{(1)}} = 180 \text{ nH},$	-	70	84	
Turn-on energy	Eon	$C_{\sigma}^{(1)} = 180 \text{ pF}$ Energy losses include	-	0.070	0.081	mJ
Turn-off energy	E _{off}	"tail" and diode	-	0.061	0.079	
Total switching energy	E _{ts}	reverse recovery.	-	0.131	0.160	

Switching Characteristic, Inductive Load, at T_i =150 °C

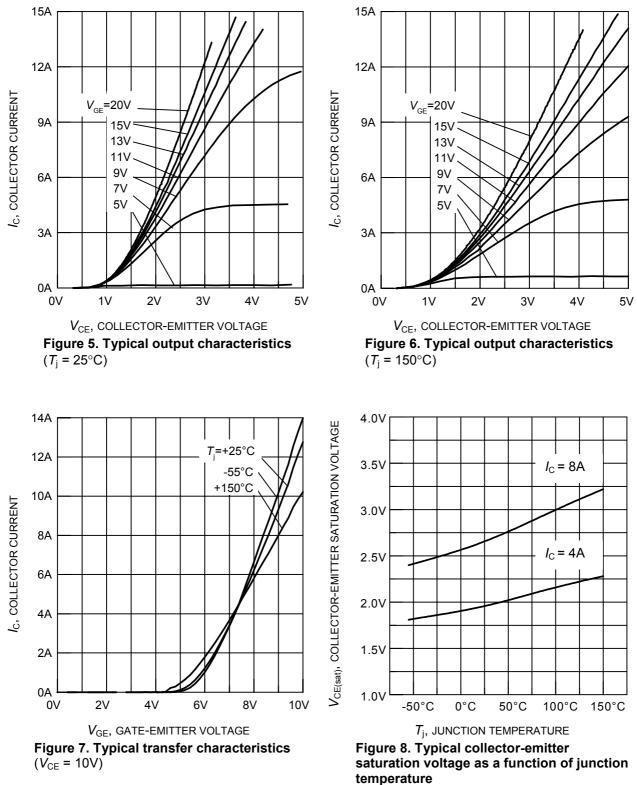
Parameter	Symbol	Conditions		Value		
Parameter	Symbol	Conditions	min.	typ.	max.	Unit
IGBT Characteristic						
Turn-on delay time	t _{d(on)}	<i>T</i> _j =150°C	-	22	26	ns
Rise time	t _r	V _{CC} =400V, <i>I</i> _C =4A, V _{GE} =0/15V,	-	16	19	
Turn-off delay time	$t_{d(off)}$	$R_{\rm G}$ =67 Ω ,	-	264	317	
Fall time	t _f	$L_{\sigma_{1}}^{(1)} = 180 \text{ nH},$	-	104	125	1
Turn-on energy	Eon	$C_{\sigma}^{(1)} = 180 \text{ pF}$ Energy losses include	-	0.115	0.132	mJ
Turn-off energy	E _{off}	"tail" and diode	-	0.111	0.144	1
Total switching energy	E _{ts}	reverse recovery.	-	0.226	0.277	1

¹⁾ Leakage inductance L_{σ} and Stray capacity C_{σ} due to dynamic test circuit in Figure E.



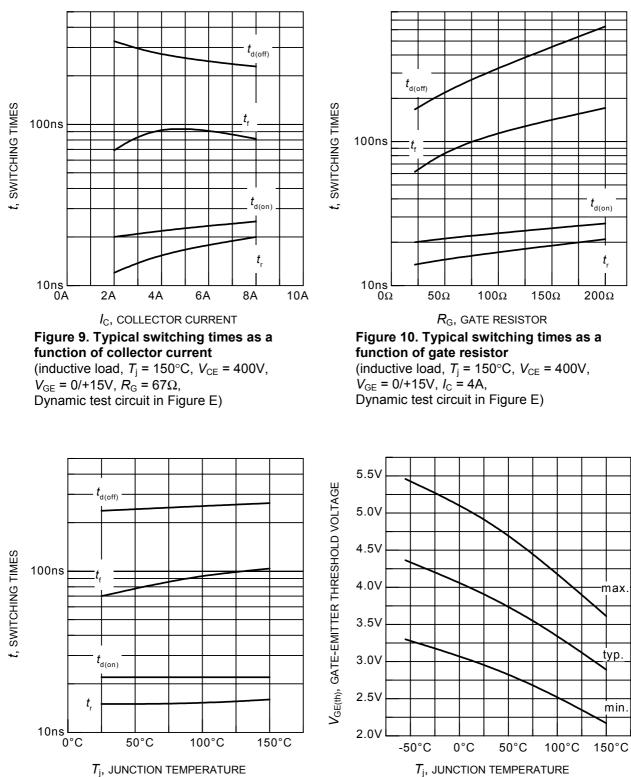


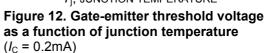




 $(V_{\rm GE} = 15V)$







6

Figure 11. Typical switching times as a

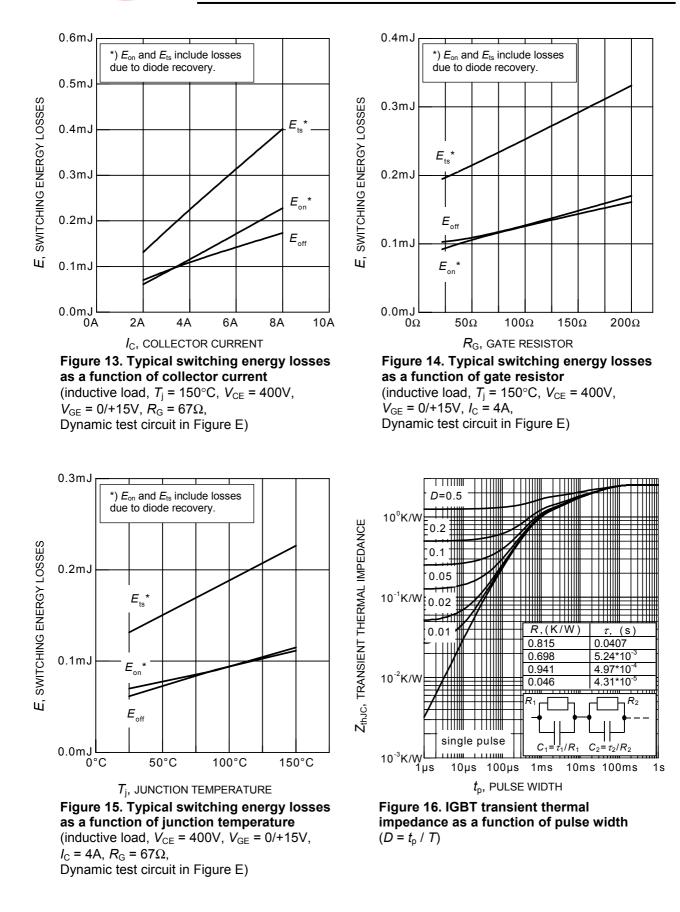
(inductive load, V_{CE} = 400V, V_{GE} = 0/+15V,

function of junction temperature

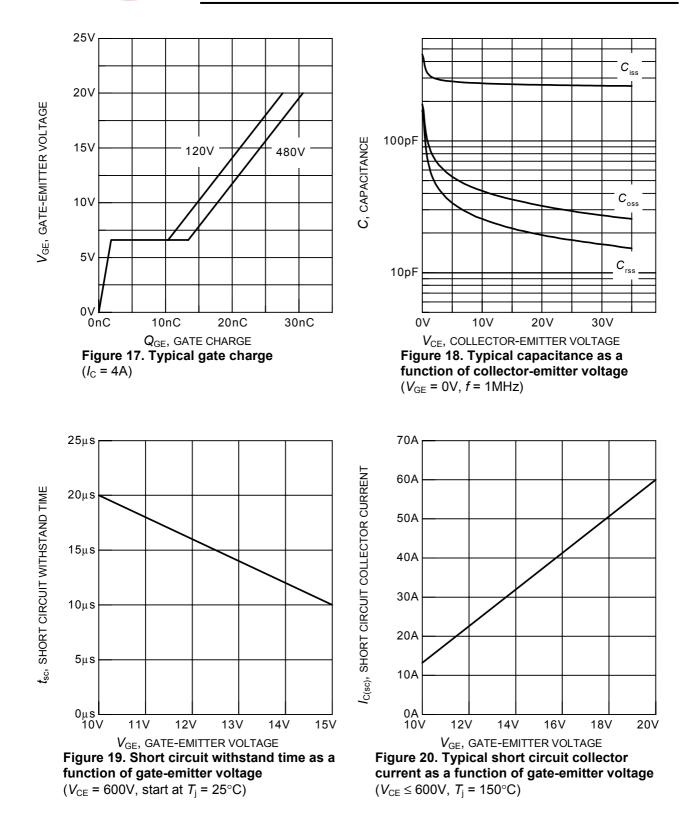
Dynamic test circuit in Figure E)

 $I_{\rm C}$ = 4A, $R_{\rm G}$ = 67 Ω ,

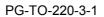


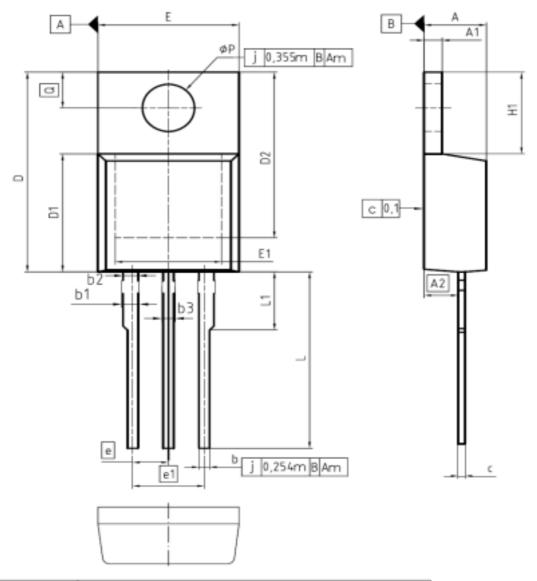




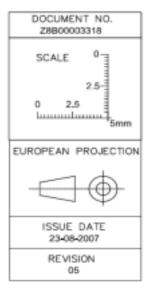






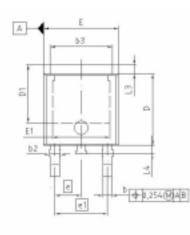


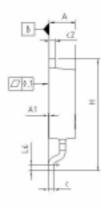
MIN MAX MIN MAX A 4.30 4.57 0.169 0.180 A1 1.17 1.40 0.046 0.055 A2 2.15 2.72 0.085 0.107 b 0.65 0.86 0.026 0.034 b1 0.95 1.40 0.037 0.055 b2 0.96 1.15 0.037 0.045 b3 0.65 1.15 0.026 0.045 c 0.33 0.60 0.013 0.024 D 14.81 15.95 0.583 0.628 D1 8.51 9.45 0.335 0.372 D2 12.19 13.10 0.480 0.516 E 9.70 10.36 0.382 0.408 E1 6.50 8.60 0.256 0.339 e 2.54 0.100 0.200 N N 3 3 3 3 H1 </th <th>Dill</th> <th>MILLIN</th> <th>ETERS</th> <th>INCH</th> <th>ES</th>	Dill	MILLIN	ETERS	INCH	ES	
A1 1.17 1.40 0.046 0.055 A2 2.15 2.72 0.085 0.107 b 0.65 0.86 0.026 0.034 b1 0.95 1.40 0.037 0.055 b2 0.95 1.15 0.037 0.045 b3 0.65 1.15 0.026 0.045 c 0.33 0.60 0.013 0.024 D 14.81 15.95 0.583 0.628 D1 8.51 9.45 0.335 0.372 D2 12.19 13.10 0.480 0.516 E 9.70 10.36 0.382 0.408 E1 6.50 8.60 0.256 0.339 e 2.54 0.100 0.200 0.100 N 3 3 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551	DIM	MIN	MAX	MIN	MAX	
A2 2.15 2.72 0.085 0.107 b 0.65 0.86 0.026 0.034 b1 0.95 1.40 0.037 0.055 b2 0.95 1.15 0.037 0.045 b3 0.65 1.15 0.026 0.045 c 0.33 0.60 0.013 0.024 D 14.81 15.95 0.583 0.628 D1 8.51 9.45 0.335 0.372 D2 12.19 13.10 0.480 0.516 E 9.70 10.36 0.382 0.408 E1 6.50 8.60 0.256 0.339 e 2.54 0.100 0.200 0 N 3 3 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189	A	4.30	4.57	0.169	0,180	
b 0,65 0,86 0,026 0,034 b1 0.95 1.40 0.037 0.055 b2 0,95 1.15 0.037 0.045 b3 0.65 1.15 0.026 0.045 c 0.33 0.60 0.013 0.024 D 14.81 15.95 0.583 0.628 D1 8,51 9.45 0.335 0.372 D2 12.19 13.10 0.480 0.516 E 9.70 10.36 0.382 0.408 E1 6,50 8,60 0.256 0.339 e 2.54 0.100 0.400 0.516 K1 5.90 6.90 0.2232 0.272 N 3 3 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189	A1	1.17	1.40	0.046	0.055	
b1 0.95 1.40 0.037 0.055 b2 0.95 1.15 0.037 0.045 b3 0.65 1.15 0.026 0.045 c 0.33 0.60 0.013 0.024 D 14.81 15.95 0.583 0.628 D1 8.51 9.45 0.335 0.372 D2 12.19 13.10 0.480 0.516 E 9.70 10.36 0.382 0.408 E1 6.50 8.60 0.256 0.339 e 2.54 0.100 0.200 0.200 N 3 3 3 1 1 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189 aP 3.60 3.89 0.142 0.153	A2	2.15	2.72	0,085	0,107	
b2 0.96 1.15 0.037 0.045 b3 0.66 1.15 0.026 0.045 c 0.33 0.60 0.013 0.024 D 14.81 15.95 0.583 0.628 D1 8.51 9.45 0.335 0.372 D2 12.19 13.10 0.480 0.516 E 9.70 10.36 0.382 0.408 E1 6.50 8.60 0.256 0.339 e 2.54 0.100 0.100 e1 5.08 0.200 0.200 N 3 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189 aP 3.60 3.89 0.142 0.153	ь	0,65	0,86	0,026	0,034	
b3 0.65 1.15 0.026 0.045 c 0.33 0.60 0.013 0.024 D 14.81 15.95 0.583 0.628 D1 8.51 9.45 0.335 0.372 D2 12.19 13.10 0.480 0.516 E 9.70 10.36 0.382 0.408 E1 6,50 8,60 0.256 0.339 e 2.54 0.100 0.100 e1 5.08 0.200 N 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189 aP 3.60 3.89 0.142 0.153	ь1	0.95	1.40	0.037	0.055	
c 0.33 0.60 0.013 0.024 D 14.81 15.95 0.583 0.628 D1 8.51 9.45 0.335 0.372 D2 12.19 13.10 0.480 0.516 E 9.70 10.36 0.382 0.408 E1 6,50 8,60 0.256 0.339 e 2.54 0.100 0.100 e1 5.08 0.200 0.200 N 3 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189 aP 3.60 3.89 0.142 0.153	b2	0,95	1.15	0,037	0,045	
D 14.81 15.95 0.583 0.628 D1 8,51 9,45 0.335 0.372 D2 12.19 13.10 0.480 0.516 E 9,70 10.36 0.302 0.408 E1 6,50 8,60 0.256 0,339 e 2.54 0.100 e1 5.08 0.200 N N 3 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189 aP 3.60 3.89 0.142 0.153	ьз	0,65	1.15	0.026	0.045	
D1 8,51 9,45 0,335 0,372 D2 12.19 13.10 0.480 0.516 E 9,70 10.36 0,382 0,408 E1 6,50 8,60 0,256 0,339 e 2.54 0.100 0.200 N 3 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0,189 aP 3.60 3.89 0.142 0.153	c	0.33	0.60	0.013	0.024	
D2 12.19 13.10 0.480 0.516 E 9.70 10.36 0.382 0.406 E1 6,50 8,60 0.256 0.339 e 2.54 0.100 e1 5.08 0.200 N 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189 aP 3.60 3.89 0.142 0.153	D	14.81	15.95	0.583	0.628	
E 9.70 10.36 0.382 0.408 E1 6,50 8,60 0.256 0,339 e 2.54 0.100 e1 5.08 0.200 N 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189 aP 3.60 3.89 0.142 0.153	D1	8,51	9,45	0,335	0,372	
E1 6,50 8,60 0,256 0,339 e 2.54 0.100 e1 5.08 0.200 N 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0,189 aP 3.60 3.89 0.142 0.153	D2	12.19	13.10	0.480	0.516	
e 2.54 0.100 e1 5.08 0.200 N 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189 aP 3.60 3.89 0.142 0.153	E	9.70	10.36	0.382	0,408	
e1 5.08 0.200 N 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189 aP 3.60 3.89 0.142 0.153	E1	6,50	8,60	0,256	0,339	
N 3 3 H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0,189 aP 3.60 3.89 0.142 0.153	e	2	54	0.100		
H1 5.90 6.90 0.232 0.272 L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189 aP 3.60 3.89 0.142 0.153	e1	5.	08	0.2	00	
L 13.00 14.00 0.512 0.551 L1 - 4.80 - 0.189 aP 3.60 3.89 0.142 0.153	N		3		3	
L1 - 4.80 - 0.189 @P 3.60 3.89 0.142 0.153	H1	5.90	6.90	0.232	0.272	
eP 3.60 3.89 0.142 0.153	L	13.00	14.00	0.512	0.551	
	L1	-	4.80	-	0,189	
Q 2.60 3.00 0.102 0.118	eP	3.60	3.89	0.142	0.153	
	Q	2.60	3.00	0.102	0,118	

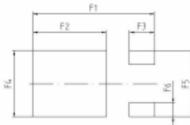




P-TO252-3-11







DM	MILLIN	ETERS	INC	-ES
UNIN	MIN	MAX	MIN	MAX
A	2.184	2.388	D.068	0.094
A1	0.000	0.150	0.000	0.006
ь	0.835	0.889	0.025	0.035
p3	0.650	1.150	0.025	0.045
b3	5.004	5.500	0.197	0.217
0	0,480	0.580	0.018	0.023
62	0,460	0.960	0.018	0.039
D	5.969	6.223	0.235	0.245
D1	5.020	5.320	D.198	0.209
E	6.400	6.734	0.252	0.265
E1	4.900	5.100	D.193	0.201
	2.2	86	0.0	190
e1	4,5	72	0.1	183-
N	3	;		3
н	9,400	10.094	0.370	0.397
L3	0.900	1,118	0.095	0.044
L4	0.650	1.018	0.025	0.040
LG	0.510	0.685	0.029	0.027
P1	10.500	10.700	0.413	0,421
F2	6.300	6.500	0.248	0.256
F3	2.900	2.300	0.063	0.091
F4	5.700	5.900	0.224	0.232
FS .	5,660	5.860	D.222	0.231
F6	1.100	1.300	D.D43	0.051



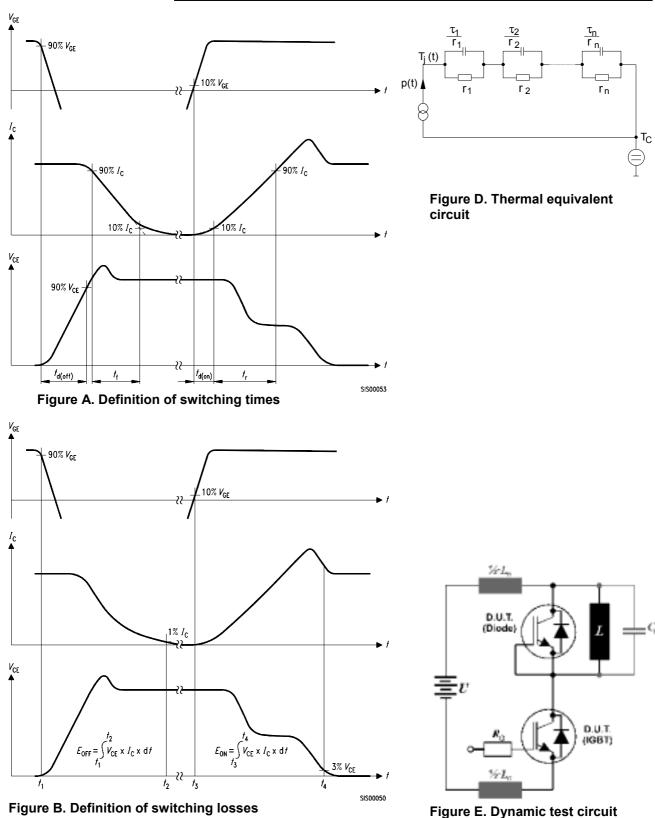


Figure E. Dynamic test circuit Leakage inductance L_{σ} =180nH and Stray capacity C_{σ} =180pF.

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